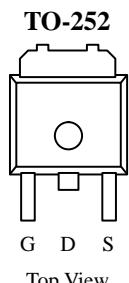


P-Channel 30-V (D-S), 150°C MOSFET

Product Summary

V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A) ^a
-30	0.015 @ $V_{GS} = -10$ V	± 13
	0.024 @ $V_{GS} = -4.5$ V	± 8

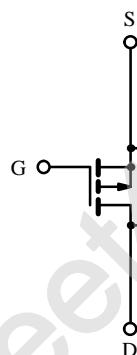
TrenchFET™
Power MOSFETs



Drain Connected to Tab

Top View

Order Number:
SUD45P03-15



P-Channel MOSFET

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^b	I_D	± 13	A
		± 8	
Pulsed Drain Current	I_{DM}	± 100	A
Continuous Source Current (Diode Conduction)	I_S	-13	
Maximum Power Dissipation ^b	P_D	70	W
		4 ^a	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150	°C

Thermal Resistance Ratings

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^b	R_{thJA}		30	°C/W
Maximum Junction-to-Case	R_{thJC}		1.8	°C/W

Notes

- a. Calculated Rating for $T_A = 25^\circ\text{C}$, for comparison purposes only. This cannot be used as continuous rating (see Absolute Maximum Ratings and Typical Characteristics).
- b. Surface Mounted on FR4 Board, $t \leq 10$ sec.

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70267.

Specifications ($T_J = 25^\circ\text{C}$ Unless Otherwise Noted)

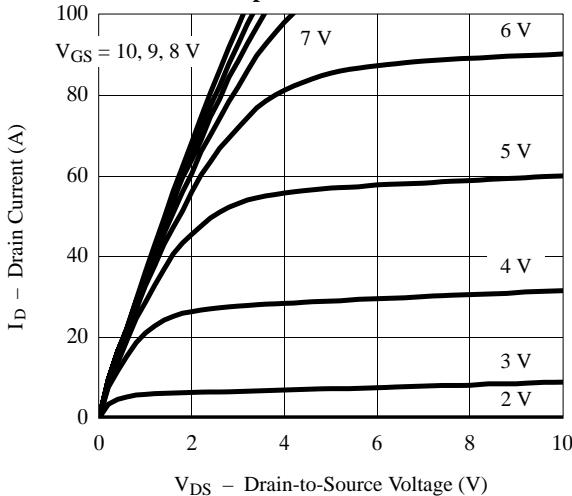
Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-30			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250 \mu\text{A}$	-1.0			
Gate-Body Leakage	I_{GSS}	$V_{\text{DS}} = 0 \text{ V}, V_{\text{GS}} = \pm 20 \text{ V}$		± 100		nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = -30 \text{ V}, V_{\text{GS}} = 0 \text{ V}$		-1		μA
		$V_{\text{DS}} = -30 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 125^\circ\text{C}$		-50		
On-State Drain Current ^b	$I_{\text{D}(\text{on})}$	$V_{\text{DS}} = -5 \text{ V}, V_{\text{GS}} = -10 \text{ V}$	-50			A
		$V_{\text{DS}} = -5 \text{ V}, V_{\text{GS}} = -4.5 \text{ V}$	-20			
Drain-Source On-State Resistance ^b	$r_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -10 \text{ V}, I_D = -13 \text{ A}$		0.012	0.015	Ω
		$V_{\text{GS}} = -10 \text{ V}, I_D = -13 \text{ A}, T_J = 125^\circ\text{C}$		0.018	0.026	
		$V_{\text{GS}} = -4.5 \text{ V}, I_D = -13 \text{ A}$		0.020	0.024	
Forward Transconductance ^b	g_{fs}	$V_{\text{DS}} = -15 \text{ V}, I_D = -13 \text{ A}$	20			S
Dynamic^a						
Input Capacitance	C_{iss}	$V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = -25 \text{ V}, F = 1 \text{ MHz}$		3200		pF
Output Capacitance	C_{oss}			800		
Reverse Transfer Capacitance	C_{rss}			280		
Total Gate Charge ^c	Q_g	$V_{\text{DS}} = -15 \text{ V}, V_{\text{GS}} = -10 \text{ V}, I_D = -45 \text{ A}$		50	125	nC
Gate-Source Charge ^c	Q_{gs}			14		
Gate-Drain Charge ^c	Q_{gd}			6.2		
Turn-On Delay Time ^c	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -15 \text{ V}, R_L = 0.33 \Omega$ $I_D \approx -45 \text{ A}, V_{\text{GEN}} = -10 \text{ V}, R_G = 2.4 \Omega$		13	20	ns
Rise Time ^c	t_r			10	20	
Turn-Off Delay Time ^c	$t_{\text{d}(\text{off})}$			50	100	
Fall Time ^c	t_f			20	40	
Source-Drain Diode Ratings and Characteristic ($T_C = 25^\circ\text{C}$)						
Pulsed Current	I_{SM}				100	A
Diode Forward Voltage ^b	V_{SD}	$I_F = -45 \text{ A}, V_{\text{GS}} = 0 \text{ V}$		1.0	1.5	V
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = -45 \text{ A}, \text{di/dt} = 100 \text{ A}/\mu\text{s}$		55	100	ns

Notes

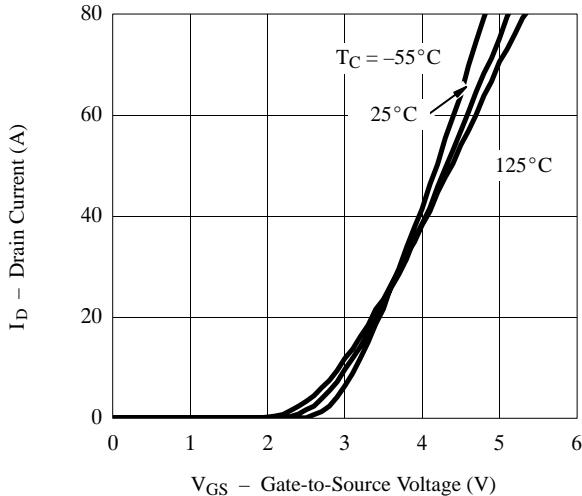
- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- c. Independent of operating temperature.

Typical Characteristics (25°C Unless Otherwise Noted)

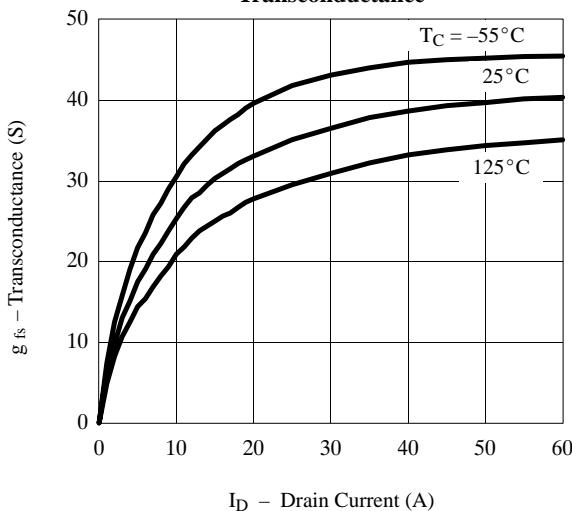
Output Characteristics



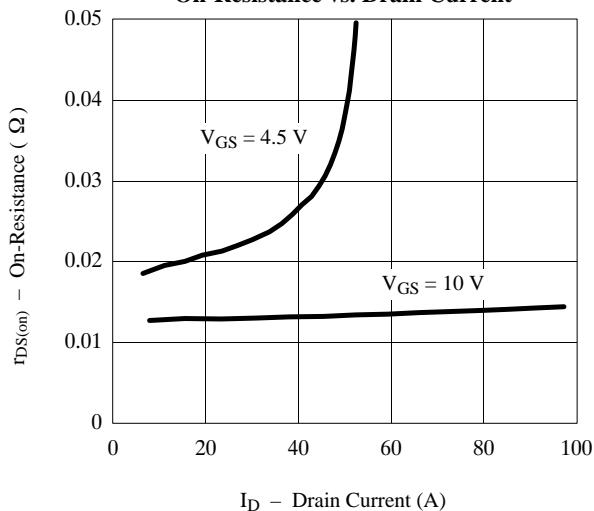
Transfer Characteristics



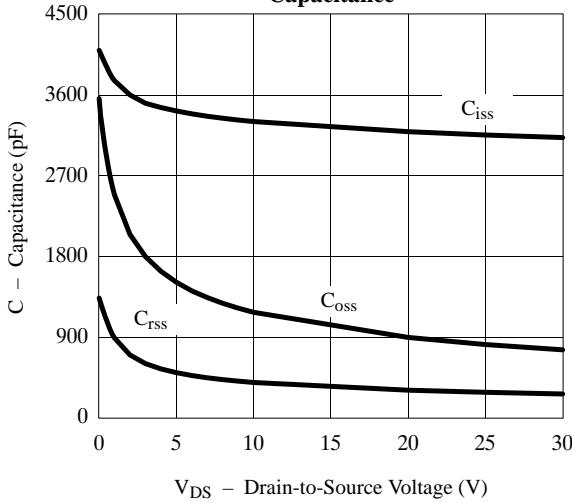
Transconductance



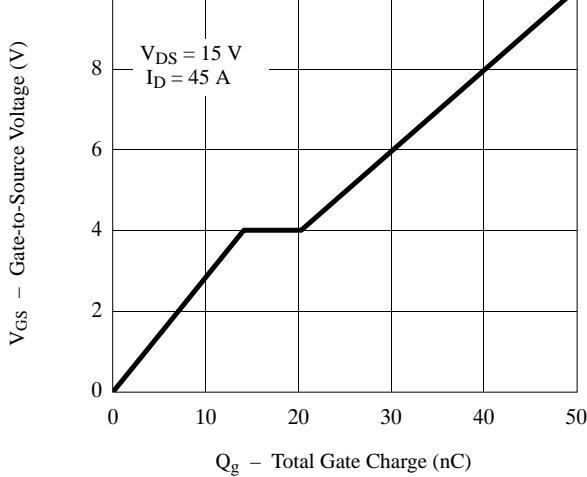
On-Resistance vs. Drain Current



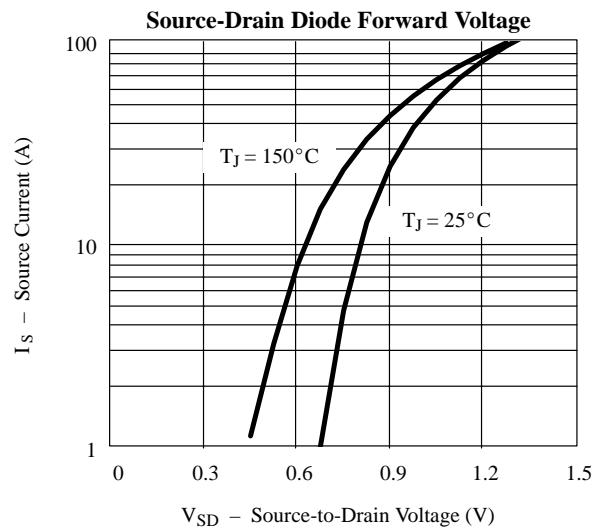
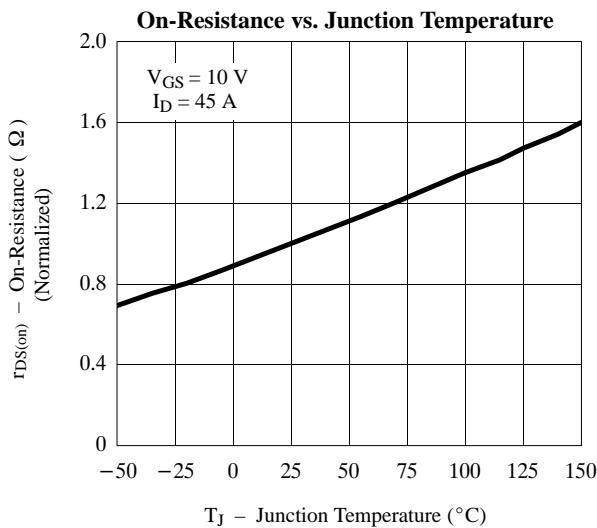
Capacitance



Gate Charge



Typical Characteristics (25°C Unless Otherwise Noted)



Thermal Ratings

